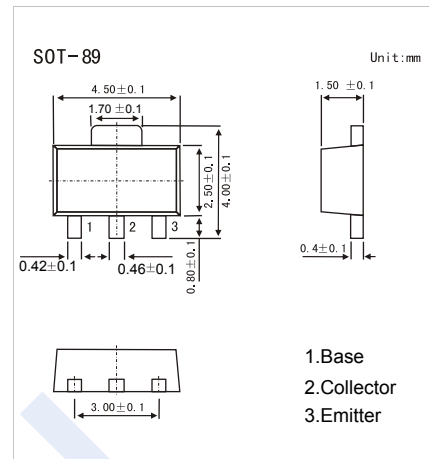


NPN Transistors

2SC5211-HF

■ Features

- High voltage $V_{CE0}=50V$.
- Small package for mounting.
- Complementary to 2SA1945-HF
- Pb-Free Package May be Available. The G-Suffix Denotes a Pb-Free Lead Finish



■ Absolute Maximum Ratings $T_a = 25^\circ C$

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V_{CB0}	55	V
Collector - Emitter Voltage	V_{CE0}	50	
Emitter - Base Voltage	V_{EB0}	4	
Collector Current - Continuous	I_C	400	mA
Collector Current - Pulse	I_{CP}	600	
Collector Power Dissipation	P_C	500	mW
Junction Temperature	T_J	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55 to 150	

■ Electrical Characteristics $T_a = 25^\circ C$

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector- base breakdown voltage	V_{CB0}	$I_C = 100 \mu A, I_E = 0$	55			V
Collector- emitter breakdown voltage	V_{CE0}	$I_C = 1 mA, R_{BE} = \infty$	50			
Emitter - base breakdown voltage	V_{EB0}	$I_E = 100 \mu A, I_C = 0$	4			
Collector-base cut-off current	I_{CBO}	$V_{CB} = 50V, I_E = 0$			1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 4V, I_C = 0$			1	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 200mA, I_B = 10mA$		0.15	0.5	V
Base - emitter saturation voltage	$V_{BE(sat)}$	$I_C = 200mA, I_B = 10mA$			1.2	
DC current gain	h_{FE}	$V_{CE} = 4V, I_C = 100mA$	90		500	
Transition frequency	f_T	$V_{CE} = 6V, I_E = -10mA$		150		MHz

■ Classification of h_{fe}

Type	2SC5211-D-HF	2SC5211-E-HF	2SC5211-F-HF
Range	90-180	150-300	250-500
Marking	TD_F	TE_F	TF_F

NPN Transistors

2SC5211-HF

■ Typical Characteristics

